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#### Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

#### Details

Product Status	Active
Core Processor	HCS12X
Core Size	16-Bit
Speed	50MHz
Connectivity	CANbus, EBI/EMI, I <sup>2</sup> C, IrDA, SCI, SPI
Peripherals	LVD, POR, PWM, WDT
Number of I/O	119
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.72V ~ 5.5V
Data Converters	A/D 24x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP
Supplier Device Package	144-LQFP (20x20)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9s12xeq512cagr

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



This section describes signals that connect off-chip. It includes a pinout diagram, a table of signal properties, and detailed discussion of signals. It is built from the signal description sections of the Block User Guides of the individual IP blocks on the device.

## 1.2.1 Device Pinout

The MC9S12XE-Family offers pin-compatible packaged devices to assist with system development and accommodate expansion of the application.

### NOTE

Smaller derivatives within the MC9S12XE-Family feature a subset of the listed modules. Refer to Appendix D Derivative Differences for more information about derivative device module subset and to Table 1-7. Port Availability by Package Option and Table 1-9. Pin-Out Summary for details of pins available in different package options.

The MC9S12XE-Family devices are offered in the following package options:

- 208-pin MAPBGA package with an external bus interface (address/data bus)
- 144-pin LQFP package with an external bus interface (address/data bus)
- 112-pin LQFP without external bus interface
- 80-pin QFP without external bus interface





Figure 6-9. Interrupt Request Configuration Data Register 3 (INT\_CFDATA3) 1. Please refer to the notes following the PRIOLVL[2:0] description below.





## 6.4.3 XGATE Requests

If the XGATE module is implemented on the device, the XINT module is also used to process all exception requests to be serviced by the XGATE module. The overall priority level of those exceptions is discussed in the subsections below.

#### 6.4.3.1 XGATE Request Prioritization

An interrupt request channel is configured to be handled by the XGATE module, if the RQST bit of the associated configuration register is set to 1 (please refer to Section 6.3.2.4, "Interrupt Request Configuration Data Registers (INT\_CFDATA0-7)"). The priority level configuration (PRIOLVL) for this channel becomes the XGATE priority which will be used to determine the highest priority XGATE request to be serviced next by the XGATE module. Additionally, XGATE interrupts may be raised by the XGATE module by setting one or more of the XGATE channel interrupt flags (by using the SIF instruction). This will result in an CPU interrupt with vector address vector base + (2 \* channel ID number), where the channel ID number corresponds to the highest set channel interrupt flag, if the XGIE and channel RQST bits are set.

The shared interrupt priority for the XGATE interrupt requests is taken from the XGATE interrupt priority configuration register (please refer to Section 6.3.2.2, "XGATE Interrupt Priority Configuration Register (INT\_XGPRIO)"). If more than one XGATE interrupt request channel becomes active at the same time, the channel with the highest vector address wins the prioritization.

## 6.4.4 Priority Decoders

The XINT module contains priority decoders to determine the priority for all interrupt requests pending for the respective target.

There are two priority decoders, one for each interrupt request target, CPU or XGATE. The function of both priority decoders is basically the same with one exception: the priority decoder for the XGATE module does not take the current XGATE thread processing level into account. Instead, XGATE requests are handed to the XGATE module including a 1-bit priority identifier. The XGATE module uses this additional information to decide if the new request can interrupt a currently running thread. The 1-bit priority identifier corresponds to the most significant bit of the priority level configuration of the requesting channel. This means that XGATE requests with priority levels 4, 5, 6 or 7 can interrupt running XGATE threads with priority levels 1, 2 and 3.

A CPU interrupt vector is not supplied until the CPU requests it. Therefore, it is possible that a higher priority interrupt request could override the original exception which caused the CPU to request the vector. In this case, the CPU will receive the highest priority vector and the system will process this exception instead of the original request.

If the interrupt source is unknown (for example, in the case where an interrupt request becomes inactive after the interrupt has been recognized, but prior to the vector request), the vector address supplied to the CPU will default to that of the spurious interrupt vector.



SC[3:0]	Description
0001	Any match triggers to state3
0010	Any match triggers to Final State
0011	Match3 triggers to State1 Other matches have no effect
0100	Match3 triggers to State3 Other matches have no effect
0101	Match3 triggers to Final State Other matches have no effect
0110	Match0 triggers to State1 Match1 triggers to State3 Other matches have no effect
0111	Match1 triggers to State3 Match0 triggers Final State Other matches have no effect
1000	Match0 triggers to State1 Match2 triggers to State3 Other matches have no effect
1001	Match2 triggers to State3 Match0 triggers Final State Other matches have no effect
1010	Match1 triggers to State1 Match3 triggers to State3 Other matches have no effect
1011	Match3 triggers to State3 Match1 triggers Final State Other matches have no effect
1100	Match2 triggers to State1 Match3 trigger to Final State
1101	Match2 has no affect, all other matches (M0,M1,M3) trigger to Final State
1110	Reserved. (No match triggers state sequencer transition)
1111	Reserved. (No match triggers state sequencer transition)

Table 8-25. State2 — Sequencer Next State Selection (continued)

The trigger priorities described in Table 8-42 dictate that in the case of simultaneous matches, the match on the lower channel number (0,1,2,3) has priority. The SC[3:0] encoding ensures that a match leading to final state has priority over all other matches.

#### 8.3.2.7.3 Debug State Control Register 3 (DBGSCR3)



#### Figure 8-11. Debug State Control Register 3 (DBGSCR3)

Read: If COMRV[1:0] = 10

Write: If COMRV[1:0] = 10 and S12XDBG is not armed.

This register is visible at 0x0027 only with COMRV[1:0] = 10. The state control register three selects the targeted next state whilst in State3. The matches refer to the match channels of the comparator match control logic as depicted in Figure 8-1 and described in Section 8.3.2.8.1. Comparators must be enabled by setting the comparator enable bit in the associated DBGXCTL control register.

#### Table 8-26. DBGSCR3 Field Descriptions

Field	Description
3–0 SC[3:0]	These bits select the targeted next state whilst in State3, based upon the match event.

Field	Description
6 CSZ	<ul> <li>Access Type Indicator — This bit indicates if the access was a byte or word size access. This bit only contains valid information when tracing CPU12X activity in Detail Mode.</li> <li>0 Word Access</li> <li>1 Byte Access</li> </ul>
5 CRW	<ul> <li>Read Write Indicator — This bit indicates if the corresponding stored address corresponds to a read or write access. This bit only contains valid information when tracing CPU12X activity in Detail Mode.</li> <li>Write Access</li> <li>Read Access</li> </ul>
4 COCF	<ul> <li>CPU12X Opcode Fetch Indicator — This bit indicates if the stored address corresponds to an opcode fetch cycle. This bit only contains valid information when tracing the XGATE accesses in Detail Mode.</li> <li>0 Stored information does not correspond to opcode fetch cycle</li> <li>1 Stored information corresponds to opcode fetch cycle</li> </ul>
3 XACK	<ul> <li>XGATE Access Indicator — This bit indicates if the stored XGATE address corresponds to a free cycle. This bit only contains valid information when tracing the CPU12X accesses in Detail Mode.</li> <li>0 Stored information corresponds to free cycle</li> <li>1 Stored information does not correspond to free cycle</li> </ul>
2 XSZ	Access Type Indicator — This bit indicates if the access was a byte or word size access. This bit only contains valid information when tracing XGATE activity in Detail Mode. 0 Word Access 1 Byte Access
1 XRW	<ul> <li>Read Write Indicator — This bit indicates if the corresponding stored address corresponds to a read or write access. This bit only contains valid information when tracing XGATE activity in Detail Mode.</li> <li>0 Write Access</li> <li>1 Read Access</li> </ul>
0 XOCF	<ul> <li>XGATE Opcode Fetch Indicator — This bit indicates if the stored address corresponds to an opcode fetch cycle. This bit only contains valid information when tracing the CPU12X accesses in Detail Mode.</li> <li>0 Stored information does not correspond to opcode fetch cycle</li> <li>1 Stored information corresponds to opcode fetch cycle</li> </ul>

#### Table 8-46. CXINF Field Descriptions (continued)

#### 8.4.5.4 Reading Data from Trace Buffer

The data stored in the Trace Buffer can be read using either the background debug module (BDM) module, the XGATE or the CPU12X provided the S12XDBG module is not armed, is configured for tracing and the system not secured. When the ARM bit is written to 1 the trace buffer is locked to prevent reading. The trace buffer can only be unlocked for reading by an aligned word write to DBGTB when the module is disarmed.

The Trace Buffer can only be read through the DBGTB register using aligned word reads, any byte or misaligned reads return 0 and do not cause the trace buffer pointer to increment to the next trace buffer address. The Trace Buffer data is read out first-in first-out. By reading CNT in DBGCNT the number of valid 64-bit lines can be determined. DBGCNT will not decrement as data is read.

Whilst reading an internal pointer is used to determine the next line to be read. After a tracing session, the pointer points to the oldest data entry, thus if no overflow has occurred, the pointer points to line0, otherwise it points to the line with the oldest entry. The pointer is initialized by each aligned write to DBGTBH to point to the oldest data again. This enables an interrupted trace buffer read sequence to be easily restarted from the oldest data entry.



Field	Description
11 XGFACTM	<ul> <li>XGFACT Mask — This bit controls the write access to the XGFACT bit. The XGFACT bit can only be set or cleared if a "1" is written to the XGFACTM bit in the same register access.</li> <li>Read: This bit will always read "0".</li> <li>Write:</li> <li>0 Disable write access to the XGFACT in the same bus cycle</li> <li>1 Enable write access to the XGFACT in the same bus cycle</li> </ul>
9 XGSWEFM	<ul> <li>XGSWEF Mask — This bit controls the write access to the XGSWEF bit. The XGSWEF bit can only be cleared if a "1" is written to the XGSWEFM bit in the same register access.</li> <li>Read: <ul> <li>This bit will always read "0".</li> </ul> </li> <li>Write: <ul> <li>Disable write access to the XGSWEF in the same bus cycle</li> <li>Enable write access to the XGSWEF in the same bus cycle</li> </ul> </li> </ul>
8 XGIEM	<ul> <li>XGIE Mask — This bit controls the write access to the XGIE bit. The XGIE bit can only be set or cleared if a "1" is written to the XGIEM bit in the same register access.</li> <li>Read: This bit will always read "0".</li> <li>Write:</li> <li>0 Disable write access to the XGIE in the same bus cycle</li> <li>1 Enable write access to the XGIE in the same bus cycle</li> </ul>
7 XGE	<ul> <li>XGATE Module Enable (Request Enable)— This bit enables incoming XGATE requests from the S12X_INT module. If the XGE bit is cleared, pending XGATE requests will be ignored. The thread that is executed by the RISC core while the XGE bit is cleared will continue to run.</li> <li>Read:</li> <li>0 Incoming requests are disabled</li> <li>1 Incoming requests are enabled</li> <li>Write:</li> <li>0 Disable incoming requests</li> <li>1 Enable incoming requests</li> </ul>
6 XGFRZ	<ul> <li>Halt XGATE in Freeze Mode — The XGFRZ bit controls the XGATE operation in Freeze Mode (BDM active).</li> <li>Read:</li> <li>0 RISC core operates normally in Freeze (BDM active)</li> <li>1 RISC core stops in Freeze Mode (BDM active)</li> <li>Write:</li> <li>0 Don't stop RISC core in Freeze Mode (BDM active)</li> <li>1 Stop RISC core in Freeze Mode (BDM active)</li> </ul>
5 XGDBG	<ul> <li>XGATE Debug Mode — This bit indicates that the XGATE is in Debug Mode (see Section 10.6, "Debug Mode").</li> <li>Debug Mode can be entered by Software Breakpoints (BRK instruction), Tagged or Forced Breakpoints (see S12X_DBG Section), or by writing a "1" to this bit.</li> <li>Read: <ul> <li>Read:</li> <li>RISC core is not in Debug Mode</li> <li>RISC core is in Debug Mode</li> </ul> </li> <li>Write: <ul> <li>Leave Debug Mode</li> <li>Enter Debug Mode</li> </ul> </li> <li>Note: Freeze Mode and Software Error Interrupts have no effect on the XGDBG bit.</li> </ul>

#### Table 10-2. XGMCTL Field Descriptions (Sheet 2 of 3)





#### Bit Test Immediate 8 bit Constant (Low Byte)



#### Operation

RD.L & IMM8  $\Rightarrow$  NONE

Performs a bit wise logical AND between the low byte of register RD and an immediate 8 bit constant. Only the condition code flags get updated, but no result is written back.

#### **CCR Effects**

Ν	Z	V	С
Δ	Δ	0	_

- N: Set if bit 7 of the result is set; cleared otherwise.
- Z: Set if the 8 bit result is \$00; cleared otherwise.
- V: 0; cleared.
- C: Not affected.

#### Code and CPU Cycles

Source Form	Address Mode	Machine Code						e Code	Cycles
BITL RD, #IMM8	IMM8	1	0	0	1	0	RD	IMM8	Р



## COM

## One's Complement

# COM

#### Operation

 $\sim$ RS ⇒ RD (translates to XNOR RD, R0, RS)  $\sim$ RD ⇒ RD (translates to XNOR RD, R0, RD)

Performs a one's complement on a general purpose register.

#### **CCR Effects**

Ν	Ζ	V	С
Δ	Δ	0	

- N: Set if bit 15 of the result is set; cleared otherwise.
- Z: Set if the result is \$0000; cleared otherwise.
- V: 0; cleared.
- C: Not affected.

### Code and CPU Cycles

Source Form	Address Mode		Machine Code							Cycles				
COM RD, RS	TRI	0	0	0	1	0	RD	0	0	0	RS	1	1	Р
COM RD	TRI	0	0	0	1	0	RD	0	0	0	RD	1	1	Р



- Illegal address reset
- COP reset
- Loss of clock reset
- External pin reset
- Real-Time Interrupt (RTI)

## 11.1.2 Modes of Operation

This subsection lists and briefly describes all operating modes supported by the S12XECRG.

• Run Mode

All functional parts of the S12XECRG are running during normal Run Mode. If RTI or COP functionality is required the individual bits of the associated rate select registers (COPCTL, RTICTL) have to be set to a non zero value.

• Wait Mode

In this mode the IPLL can be disabled automatically depending on the PLLWAI bit.

• Stop Mode

Depending on the setting of the PSTP bit Stop Mode can be differentiated between Full Stop Mode (PSTP = 0) and Pseudo Stop Mode (PSTP = 1).

— Full Stop Mode

The oscillator is disabled and thus all system and core clocks are stopped. The COP and the RTI remain frozen.

Pseudo Stop Mode

The oscillator continues to run and most of the system and core clocks are stopped. If the respective enable bits are set the COP and RTI will continue to run, else they remain frozen.

Self Clock Mode

Self Clock Mode will be entered if the Clock Monitor Enable Bit (CME) and the Self Clock Mode Enable Bit (SCME) are both asserted and the clock monitor in the oscillator block detects a loss of clock. As soon as Self Clock Mode is entered the S12XECRG starts to perform a clock quality check. Self Clock Mode remains active until the clock quality check indicates that the required quality of the incoming clock signal is met (frequency and amplitude). Self Clock Mode should be used for safety purposes only. It provides reduced functionality to the MCU in case a loss of clock is causing severe system conditions.

## 11.1.3 Block Diagram

Figure 11-1 shows a block diagram of the S12XECRG.

#### ter 13 Analog-to-Digital Converter (ADC12B16CV1)

Only analog input signals within the potential range of  $V_{RL}$  to  $V_{RH}$  (A/D reference potentials) will result in a non-railed digital output code.

## 13.4.2 Digital Sub-Block

This subsection explains some of the digital features in more detail. See Section 13.3.2, "Register Descriptions" for all details.

## 13.4.2.1 External Trigger Input

The external trigger feature allows the user to synchronize ATD conversions to the external environment events rather than relying on software to signal the ATD module when ATD conversions are to take place. The external trigger signal (out of reset ATD channel 15, configurable in ATDCTL1) is programmable to be edge or level sensitive with polarity control. Table 13-23 gives a brief description of the different combinations of control bits and their effect on the external trigger function.

ETRIGLE	ETRIGP	ETRIGE	SCAN	Description
X	х	0	0	Ignores external trigger. Performs one conversion sequence and stops.
X	х	0	1	Ignores external trigger. Performs continuous conversion sequences.
0	0	1	х	Falling edge triggered. Performs one conversion sequence per trigger.
0	1	1	х	Rising edge triggered. Performs one conversion sequence per trigger.
1	0	1	х	Trigger active low. Performs continuous conversions while trigger is active.
1	1	1	x	Trigger active high. Performs continuous conversions while trigger is active.

Table 13-23. External Trigger Control Bits

During a conversion, if additional active edges are detected the overrun error flag ETORF is set.

In either level or edge triggered modes, the first conversion begins when the trigger is received.

Once ETRIGE is enabled, conversions cannot be started by a write to ATDCTL5, but rather must be triggered externally.

If the level mode is active and the external trigger both de-asserts and re-asserts itself during a conversion sequence, this does not constitute an overrun. Therefore, the flag is not set. If the trigger is left asserted in level mode while a sequence is completing, another sequence will be triggered immediately.



#### 14.3.2.30 8-Bit Pulse Accumulators Holding Registers (PA3H–PA0H)

Module Base + 0x0032

	7	6	5	4	3	2	1	0			
R	PA3H7	PA3H6	PA3H5	PA3H4	PA3H3	PA3H2	PA3H1	PA3H0			
W											
Reset	0	0	0	0	0	0	0	0			
	= Unimplemented or Reserved										



Module Base + 0x0033

	7	6	5	4	3	2	1	0			
R	PA2H7	PA2H6	PA2H5	PA2H4	PA2H3	PA2H2	PA2H1	PA2H0			
W											
Reset	0	0	0	0	0	0	0	0			
	= Unimplemented or Reserved										
Figure 14-54. 8-Bit Pulse Accumulators Holding Register 2 (PA2H)											

Module Base + 0x0034



#### Figure 14-55. 8-Bit Pulse Accumulators Holding Register 1 (PA1H)

Module Base + 0x0035

	7	6	5	4	3	2	1	0
R	PA0H7	PA0H6	PA0H5	PA0H4	PA0H3	PA0H2	PA0H1	PA0H0
W								
Reset	0	0	0	0	0	0	0	0
		= Unimplemented or Reserved						

#### Figure 14-56. 8-Bit Pulse Accumulators Holding Register 0 (PA0H)

Read: Anytime.

Write: Has no effect.

All bits reset to zero.

These registers are used to latch the value of the corresponding pulse accumulator when the related bits in register ICPAR are enabled (see Section 14.4.1.3, "Pulse Accumulators").

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Offset Address	Register	Access			
0x00X0	IDR0 — Identifier Register 0	R/W			
0x00X1	IDR1 — Identifier Register 1	R/W			
0x00X2	IDR2 — Identifier Register 2	R/W			
0x00X3	IDR3 — Identifier Register 3	R/W			
0x00X4	DSR0 — Data Segment Register 0	R/W			
0x00X5	DSR1 — Data Segment Register 1	R/W			
0x00X6	DSR2 — Data Segment Register 2	R/W			
0x00X7	DSR3 — Data Segment Register 3	R/W			
0x00X8	DSR4 — Data Segment Register 4	R/W			
0x00X9	DSR5 — Data Segment Register 5				
0x00XA	DSR6 — Data Segment Register 6				
0x00XB	DSR7 — Data Segment Register 7				
0x00XC	DLR — Data Length Register				
0x00XD	TBPR — Transmit Buffer Priority Register <sup>(1)</sup>	R/W			
0x00XE	TSRH — Time Stamp Register (High Byte) R				
0x00XF	TSRL — Time Stamp Register (Low Byte)     R				

Table 16-26.	Message Buffer	Organization
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Not applicable for receive buffers

Figure 16-24 shows the common 13-byte data structure of receive and transmit buffers for extended identifiers. The mapping of standard identifiers into the IDR registers is shown in Figure 16-25.

All bits of the receive and transmit buffers are 'x' out of reset because of RAM-based implementation<sup>1</sup>. All reserved or unused bits of the receive and transmit buffers always read 'x'.

1. Exception: The transmit buffer priority registers are 0 out of reset.

L L 

I I



## 19.4.2 PWM Channel Timers

The main part of the PWM module are the actual timers. Each of the timer channels has a counter, a period register and a duty register (each are 8-bit). The waveform output period is controlled by a match between the period register and the value in the counter. The duty is controlled by a match between the duty register and the counter value and causes the state of the output to change during the period. The starting polarity of the output is also selectable on a per channel basis. Shown below in Figure 19-19 is the block diagram for the PWM timer.



PWMEx



### 19.4.2.1 PWM Enable

Each PWM channel has an enable bit (PWMEx) to start its waveform output. When any of the PWMEx bits are set (PWMEx = 1), the associated PWM output signal is enabled immediately. However, the actual PWM waveform is not available on the associated PWM output until its clock source begins its next cycle due to the synchronization of PWMEx and the clock source. An exception to this is when channels are concatenated. Refer to Section 19.4.2.7, "PWM 16-Bit Functions" for more detail.

#### NOTE

The first PWM cycle after enabling the channel can be irregular.



**D-Flash Sector** — The D-Flash sector is the smallest portion of the D-Flash memory that can be erased. The D-Flash sector consists of four 64 byte rows for a total of 256 bytes.

**EEE (Emulated EEPROM)** — A method to emulate the small sector size features and endurance characteristics associated with an EEPROM.

**EEE IFR** — Nonvolatile information register located in the D-Flash block that contains data required to partition the D-Flash memory and buffer RAM for EEE. The EEE IFR is visible in the global memory map by setting the EEEIFRON bit in the MMCCTL1 register.

**NVM Command Mode** — An NVM mode using the CPU to setup the FCCOB register to pass parameters required for Flash command execution.

**Phrase** — An aligned group of four 16-bit words within the P-Flash memory. Each phrase includes eight ECC bits for single bit fault correction and double bit fault detection within the phrase.

P-Flash Memory — The P-Flash memory constitutes the main nonvolatile memory store for applications.

**P-Flash Sector** — The P-Flash sector is the smallest portion of the P-Flash memory that can be erased. Each P-Flash sector contains 1024 bytes.

**Program IFR** — Nonvolatile information register located in the P-Flash block that contains the Device ID, Version ID, and the Program Once field. The Program IFR is visible in the global memory map by setting the PGMIFRON bit in the MMCCTL1 register.

## 25.1.2 Features

#### 25.1.2.1 P-Flash Features

- 256 Kbytes of P-Flash memory composed of two 128 Kbyte Flash blocks. The 128 Kbyte Flash blocks are each divided into 128 sectors of 1024 bytes.
- Single bit fault correction and double bit fault detection within a 64-bit phrase during read operations
- Automated program and erase algorithm with verify and generation of ECC parity bits
- Fast sector erase and phrase program operation
- Ability to program up to one phrase in each P-Flash block simultaneously
- Flexible protection scheme to prevent accidental program or erase of P-Flash memory

#### 25.1.2.2 D-Flash Features

- Up to 32 Kbytes of D-Flash memory with 256 byte sectors for user access
- Dedicated commands to control access to the D-Flash memory over EEE operation
- Single bit fault correction and double bit fault detection within a word during read operations
- Automated program and erase algorithm with verify and generation of ECC parity bits
- Fast sector erase and word program operation
- Ability to program up to four words in a burst sequence

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ter 25 256 KByte Flash Module (S12XFTM256K2V1)



Figure 25-3. EEE Resource Memory Map

The Full Partition D-Flash command (see Section 25.4.2.15) is used to program the EEE nonvolatile information register fields where address  $0x12\_0000$  defines the D-Flash partition for user access and address  $0x12\_0004$  defines the buffer RAM partition for EEE operations.



#### 25.3.2.9.1 P-Flash Protection Restrictions

The general guideline is that P-Flash protection can only be added and not removed. Table 25-23 specifies all valid transitions between P-Flash protection scenarios. Any attempt to write an invalid scenario to the FPROT register will be ignored. The contents of the FPROT register reflect the active protection scenario. See the FPHS and FPLS bit descriptions for additional restrictions.

From	To Protection Scenario <sup>(1)</sup>								
Protection Scenario	0	1	2	3	4	5	6	7	
0	Х	Х	Х	Х					
1		Х		Х					
2			Х	Х					
3				Х					
4				Х	Х				
5			Х	Х	Х	Х			
6		Х		Х	Х		Х		
7	Х	Х	X	X	Х	Х	Х	X	

#### Table 25-23. P-Flash Protection Scenario Transitions

1. Allowed transitions marked with X, see Figure 25-14 for a definition of the scenarios.

#### 25.3.2.10 EEE Protection Register (EPROT)

The EPROT register defines which buffer RAM EEE partition areas are protected against writes.



Offset Module Base + 0x0009

#### Figure 25-15. EEE Protection Register (EPROT)

All bits in the EPROT register are readable and writable except for RNV[6:4] which are only readable. The EPOPEN and EPDIS bits can only be written to the protected state. The EPS bits can be written anytime until the EPDIS bit is cleared. If the EPOPEN bit is cleared, the state of the EPDIS and EPS bits is irrelevant.

During the reset sequence, the EPROT register is loaded from the EEE protection byte in the Flash configuration field at global address 0x7F\_FF0D located in P-Flash memory (see Table 25-3) as indicated by reset condition F in Figure 25-15. To change the EEE protection that will be loaded during the reset sequence, the P-Flash sector containing the EEE protection byte must be unprotected, then the EEE protection byte must be programmed. If a double bit fault is detected while reading the P-Flash phrase



## 28.4 Functional Description

## 28.4.1 Flash Command Operations

Flash command operations are used to modify Flash memory contents or configure module resources for EEE operation.

The next sections describe:

- How to write the FCLKDIV register that is used to generate a time base (FCLK) derived from OSCCLK for Flash program and erase command operations
- The command write sequence used to set Flash command parameters and launch execution
- Valid Flash commands available for execution

#### 28.4.1.1 Writing the FCLKDIV Register

Prior to issuing any Flash program or erase command after a reset, the user is required to write the FCLKDIV register to divide OSCCLK down to a target FCLK of 1 MHz. Table 28-9 shows recommended values for the FDIV field based on OSCCLK frequency.

#### NOTE

Programming or erasing the Flash memory cannot be performed if the bus clock runs at less than 1 MHz. Setting FDIV too high can destroy the Flash memory due to overstress. Setting FDIV too low can result in incomplete programming or erasure of the Flash memory cells.

When the FCLKDIV register is written, the FDIVLD bit is set automatically. If the FDIVLD bit is 0, the FCLKDIV register has not been written since the last reset. If the FCLKDIV register has not been written, any Flash program or erase command loaded during a command write sequence will not execute and the ACCERR bit in the FSTAT register will set.

#### 28.4.1.2 Command Write Sequence

The Memory Controller will launch all valid Flash commands entered using a command write sequence.

Before launching a command, the ACCERR and FPVIOL bits in the FSTAT register must be clear (see Section 28.3.2.7) and the CCIF flag should be tested to determine the status of the current command write sequence. If CCIF is 0, the previous command write sequence is still active, a new command write sequence cannot be started, and all writes to the FCCOB register are ignored.

#### CAUTION

Writes to any Flash register must be avoided while a Flash command is active (CCIF=0) to prevent corruption of Flash register contents and Memory Controller behavior.



Register	Error Bit	Error Condition		
	ACCERR	Set if CCOBIX[2:0] != 101 at command launch		
		Set if command not available in current mode (see Table 28-30)		
		Set if an invalid global address [22:0] is supplied <sup>(1)</sup>		
		Set if a misaligned phrase address is supplied (global address [2:0] != 000)		
		Set if a Load Data Field command sequence is currently active and the selected block has previously been selected in the same command sequence		
FSIAI		Set if a Load Data Field command sequence is currently active and global address [17:0] does not match that previously supplied in the same command sequence		
	FPVIOL	Set if the global address [22:0] points to a protected area		
	MGSTAT1	Set if any errors have been encountered during the verify operation		
	MGSTAT0	Set if any non-correctable errors have been encountered during the verify operation		
FERSTAT	EPVIOLIF	None		

Table 28-44. Program P-Flash Command Error Handling

As defined by the memory map for FTM1024K5.

#### 28.4.2.7 Program Once Command

The Program Once command restricts programming to a reserved 64 byte field (8 phrases) in the nonvolatile information register located in P-Flash block 0. The Program Once reserved field can be read using the Read Once command as described in Section 28.4.2.4. The Program Once command must only be issued once since the nonvolatile information register in P-Flash block 0 cannot be erased. The Program Once command must not be executed from the Flash block containing the Program Once reserved field to avoid code runaway.

CCOBIX[2:0]	FCCOB Parameters			
000	0x07	Not Required		
001	Program Once phrase index (0x0000 - 0x0007)			
010	Program Once word 0 value			
011	Program Once word 1 value			
100	Program Once word 2 value			
101	Program Once word 3 value			

Table 28-45. Program Once Command FCCOB Requirements

Upon clearing CCIF to launch the Program Once command, the Memory Controller first verifies that the selected phrase is erased. If erased, then the selected phrase will be programmed and then verified with read back. The CCIF flag will remain clear, setting only after the Program Once operation has completed.

The reserved nonvolatile information register accessed by the Program Once command cannot be erased and any attempt to program one of these phrases a second time will not be allowed. Valid phrase index



## Chapter 29 1024 KByte Flash Module (S12XFTM1024K5V2)

Revision Number	Revision Date	Sections Affected	Description of Changes
V02.08	14 Nov 2007	29.5.2/29-1200 29.4.2/29-1176	<ul> <li>Changed terminology from 'word program' to "Program P-Flash' in the BDM unsecuring description, Section 29.5.2</li> <li>Added requirement that user not write any Flash module register during execution of commands 'Erase All Blocks', Section 29.4.2.8, and 'Unsecure Elash' Section 29.4.2.11</li> </ul>
		29.4.2.8/29- 1182	- Added statement that security is released upon successful completion of command 'Erase All Blocks', Section 29.4.2.8
V02.09	19 Dec 2007	29.4.2/29-1176	- Corrected Error Handling table for Full Partition D-Flash, Partition D-Flash, and EEPROM Emulation Query commands
V02.10	25 Sep 2009	29.1/29-1140 29.3.2.1/29- 1152 29.4.2.4/29- 1179 29.4.2.7/29- 1181 29.4.2.12/29- 1185 29.4.2.12/29- 1185 29.4.2.12/29- 1185 29.4.2.20/29- 1194 29.3.2/29-1150 29.3.2.1/29- 1152 29.4.1.2/29- 1171 29.6/29-1200	<ul> <li>Clarify single bit fault correction for P-Flash phrase</li> <li>Expand FDIV vs OSCCLK Frequency table</li> <li>Add statement concerning code runaway when executing Read Once command from Flash block containing associated fields</li> <li>Add statement concerning code runaway when executing Program Once command from Flash block containing associated fields</li> <li>Add statement concerning code runaway when executing Verify Backdoor Access Key command from Flash block containing associated fields</li> <li>Relate Key 0 to associated Backdoor Comparison Key address</li> <li>Change "power down reset" to "reset"</li> <li>Add ACCERR condition for Disable EEPROM Emulation command The following changes were made to clarify module behavior related to Flash register access during reset sequence and while Flash commands are active:</li> <li>Add caution concerning register writes while command is active</li> <li>Writes to FCLKDIV are allowed during reset sequence while CCIF is clear</li> <li>Add caution concerning register writes while command is active</li> <li>Writes to FCCOBIX, FCCOBHI, FCCOBLO registers are ignored during reset sequence</li> </ul>

#### Table 29-1. Revision History



Figure 29-26. Generic Flash Command Write Sequence Flowchart